

Description

ACE2372M uses advanced trench technology to provide excellent R_{DS(ON)}.

This device particularly suits for low voltage application such as power management of desktop computer or notebook computer power management, DC/DC converter.

Features

- Low r_{DS(on)} trench technology
- Low thermal impedance
- Fast switching speed

Applications:

- LED Inverter Circuits
- DC/DC Conversion Circuits
- Motor drives

Absolute Maximum Ratings

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V_{DS}	100	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current ^a	T _A =25°C	ı	0.66	А	
	T _A =70°C	- I _D	0.52		
Pulsed Drain Current ^b		I _{DM}	3		
Continuous Source Current (Diode Conduction) a		I _S	s 0.66		
Power Dissipation ^a	T _A =25°C	В	1.3	W	
	T _A =70°C	P _D	0.8	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS

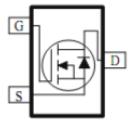
Parameter		Symbol	Maximum	Unit
Maximum Junction-to-Ambient ^a	t<=10sec	D	100	°C/W
	Steady State	$\kappa_{ heta JA}$	166	C/ VV

Notes

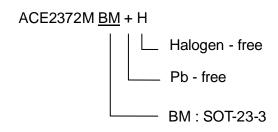
- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature



Packaging Type



Ordering information





 T_A =25°C, unless otherwise specified.

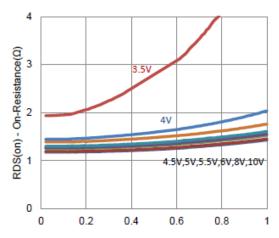
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit			
Static									
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$				V			
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	nA			
Zero Gate Voltage Drain Current		$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1				
	I _{DSS}	V _{DS} = 80V, V _{GS} = 0 V, T _J = 55°C			10	uA			
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	1			Α			
Drain-Source On-Resistance		VGS = 10 V, ID = 0.5 A			2000	mΩ			
	r _{DS(on)}	VGS = 5.5 V, ID = 0.4 A			2200				
Forward Transconductance	g _{fs}	VDS = 15 V, ID = 0.5 A		4		S			
Diode Forward Voltage	V _{SD}	$I_{S} = 0.33 \text{ A}, V_{GS} = 0 \text{ V}$		0.79		V			
	<u> </u>	Dynamic							
Total Gate Charge	Q_g			1.2		nC			
Gate-Source Charge	Q_{gs}	VDS = 50 V, VGS = 4.5 V, ID = 0.5 A		0.2					
Gate-Drain Charge	Q_{gd}]		0.8					
Turn-On Delay Time	t _{d(on)}			2					
Rise Time	t _r	$VDD = 50 \text{ V}, \text{ RL} = 100 \Omega, \text{ ID} = 0.5 \text{ A},$		4					
Turn-Off Delay Time	t _{d(off)}	VGEN = 10 V, RGEN = 6Ω		12		nS			
Fall Time	t _f			5					
Input Capacitance	C _{iss}			61					
Output Capacitance	C _{oss}	VDS = 15 V, VGS = 0 V, f =1 MHz		19		pF			
ReverseTransfer Capacitance	C_{rss}			9					

Note:

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

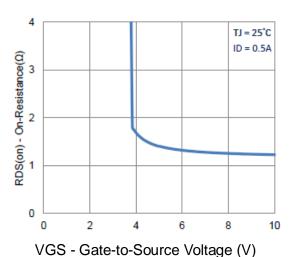


Typical Performance Characteristics (N-Channel)

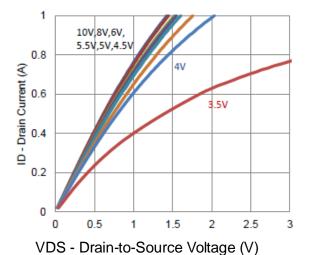


ID-Drain Current (A)

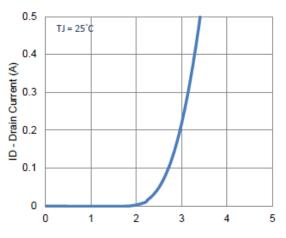
1. On-Resistance vs. Drain Current



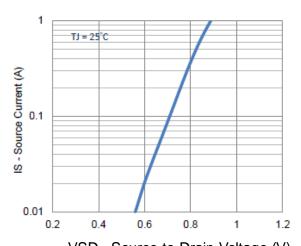
3. On-Resistance vs. Gate-to-Source Voltage



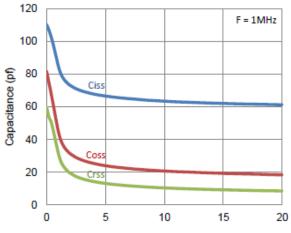
5. Output Characteristics



VGS - Gate-to-Source Voltage (V) 2. Transfer Characteristics



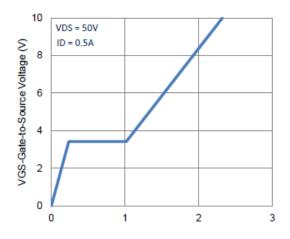
VSD - Source-to-Drain Voltage (V) 4. Drain-to-Source Forward Voltage



VDS-Drain-to-Source Voltage (V) 6. Capacitance



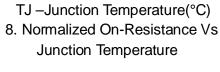
Typical Performance Characteristics

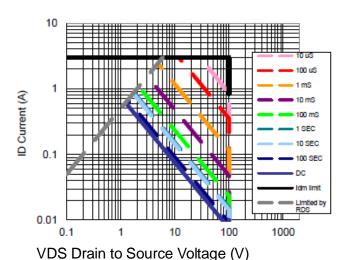


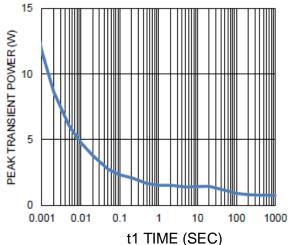
(Normalized) 1.5 -50 -25 0 25 50 75 100 125 150

2.5

Qg - Total Gate Charge (nC) 7. Gate Charge

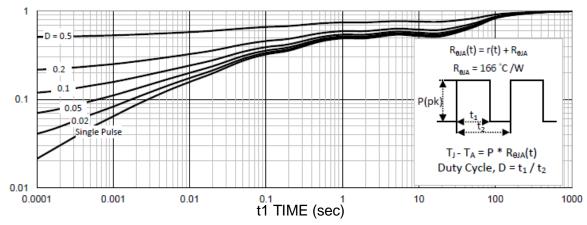






9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation

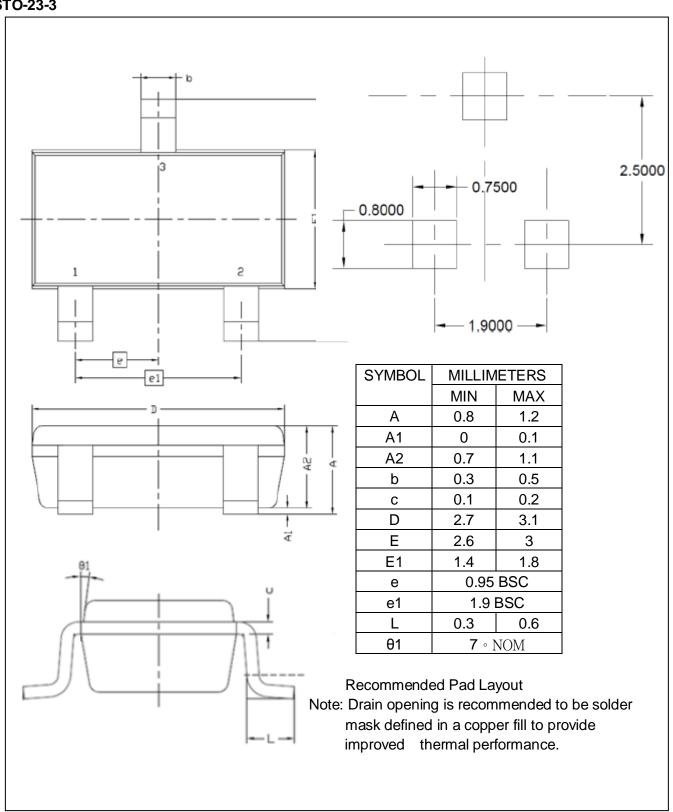


11. Normalized Thermal Transient Junction to Ambient



Packing Information

STO-23-3





Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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